TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC540F,TC74VHC540FT,TC74VHC540FK TC74VHC541F,TC74VHC541FT,TC74VHC541FK

Octal Bus Buffer

TC74VHC540F/FT/FK

Inverted, 3-State Outputs

TC74VHC541F/FT/FK

Non-Inverted, 3-State Outputs

The TC74VHC540/TC74VHC541 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

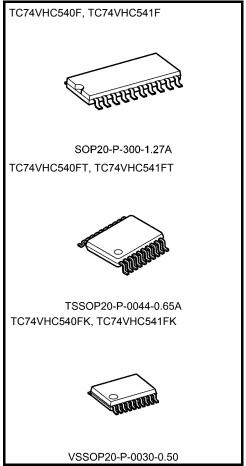
The TC74VHC540 is an inverting type, and the TC74VHC541 is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

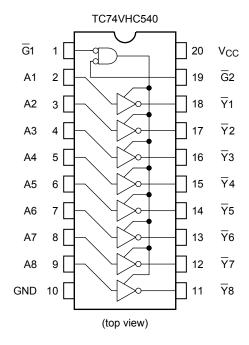
- High speed: $t_{pd} = 3.7 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A$ (max) at $T_a = 25$ °C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC \text{ (opr)}} = 2 \text{ V to } 5.5 \text{ V}$
- Low noise: VOLP = 1.2 V (max)
- Pin and function compatible with 74ALS540/541

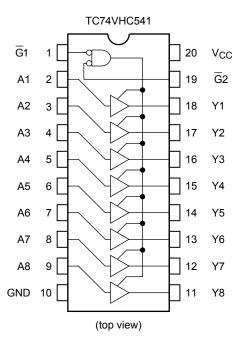


Weight

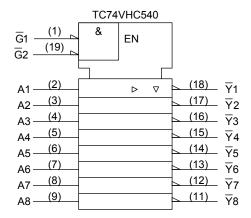
SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

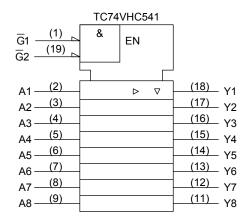
Pin Assignment





IEC Logic Symbol





Truth Table

Inputs			Outputs			
G1	G2	An	Yn	\overline{Y}_n		
Н	Х	Х	Z	Z		
Х	Н	Х	Z	Z		
L	L	Н	Н	L		
L	L	L	L	Н		

X: Don't care

Z: High impedance

Yn: TC74VHC541

Y_n: TC74VHC540

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Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	l _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	I _{CC}	±75	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	٧	
Input voltage	V _{IN}	0 to 5.5	>	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
input rise and fail time	ui/uv	0 to 20 (V _{CC} = 5 ± 0.5 V)		

Note: The operating ranges must be maintained to ensure the normal operation of the device..
Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
High-level input				2.0	1.50		_	1.50	1	V
voltage	V _{IH}		_		V _{CC} × 0.7	ı	_	V _{CC} × 0.7	ı	
Low-level input				2.0	_	_	0.50	_	0.50	
voltage	V_{IL}		_	3.0 to 5.5	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V
				2.0	1.9	2.0	_	1.9	_	
		V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
High-level output voltage	V _{OH}			4.5	4.4	4.5	_	4.4	_	V
			I _{OH} = −4 mA	3.0	2.58	_	_	2.48	-	
			$I_{OH} = -8 \text{ mA}$	4.5	3.94		_	3.80	_	
	VoL	V _{IN} = V _{IH} or V _{IL}		2.0		0.0	0.1	_	0.1	
			I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage				4.5	-	0.0	0.1	-	0.1	V
			I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
			I _{OL} = 8 mA	4.5	-	-	0.36	-	0.44	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_		±0.25		±2.50	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	-	_	±0.1	ı	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	-	_	4.0	_	40.0	μΑ



AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Te Symbol		est Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
2 3		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	OTIL	
			3.3 ± 0.3	15	_	4.8	7.0	1.0	8.5	
Propagation delay time	t_{pLH}			50	_	7.3	10.5	1.0	12.0	
(TC74VHC540)	t_{pHL}	_	5.0 ± 0.5	15	_	3.7	5.0	1.0	6.0	ns
			5.0 ± 0.5	50	_	5.2	7.0	1.0	8.0	
			3.3 ± 0.3	15	_	5.0	7.0	1.0	8.5	
Propagation delay time	t_{pLH}		3.3 ± 0.3	50	_	7.5	10.5	1.0	12.0	ns
(TC74VHC541)	t_{pHL}	_	5.0 ± 0.5	15	_	3.5	5.0	1.0	6.0	is
,				50	_	5.0	7.0	1.0	8.0	
	^t pZL t _{pZH}	R _L = 1 kΩ	3.3 ± 0.3	15	_	6.8	10.5	1.0	12.5	- ns
3-state output enable				50	_	9.3	14.0	1.0	16.0	
time			5.0 ± 0.5	15	_	4.7	7.2	1.0	8.5	
				50	_	6.2	9.2	1.0	10.5	
3-state output disable	t _{pLZ}	R _L = 1 kΩ	3.3 ± 0.3	50	_	11.2	15.4	1.0	17.5	ns
time	t_{pHZ}	KL - 1 KZ2	5.0 ± 0.5	50	_	6.0	8.8	1.0	10.0	115
Output to output skow	t _{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
Output to output skew	t _{osLH}	(Note 1)	5.0 ± 0.5	50	_	_	1.0	_	1.0	
Input capacitance	C _{IN}				_	4	10	_	10	pF
Output capacitance	C _{OUT}				_	6	_	_		pF
Power dissipation	0	TC74VHC540 TC74VHC541		_	17	_	_		pF	
capacitance (Note 2)	C _{PD}			_	18	_		_		

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$

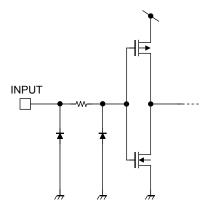
Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		- Unit
Characteristics	Symbol		V _{CC} (V)	Тур.	Limit	Offic
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.7	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.7	-1.0	>
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	l	3.5	>
Maximum low level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0		1.5	٧

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Input Equivalent Circuit

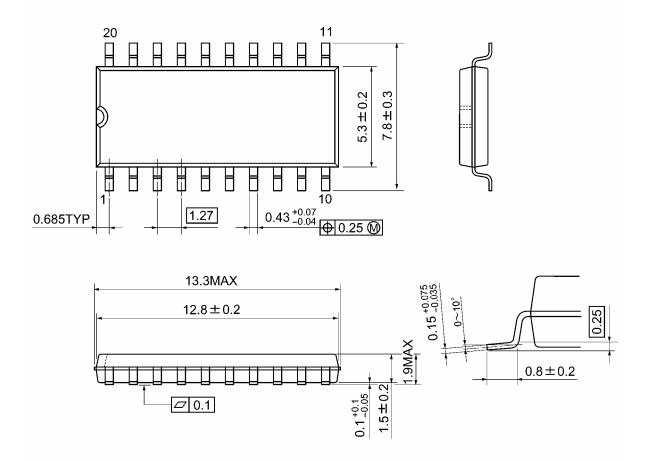


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Package Dimensions

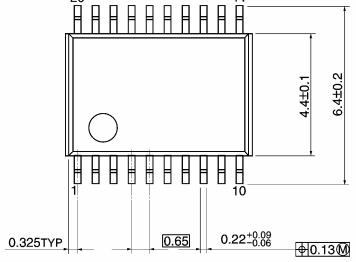
SOP20-P-300-1.27A Unit: mm

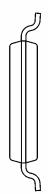


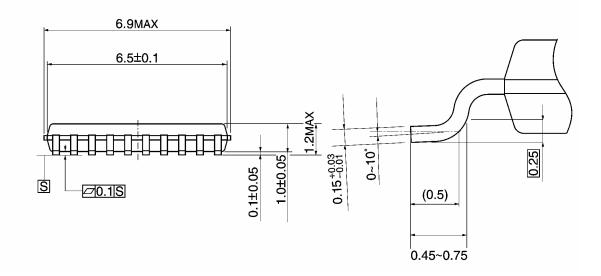
Weight: 0.22 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm





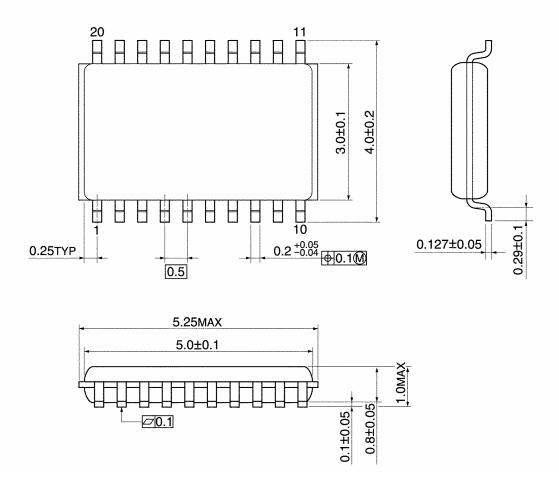


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Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



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Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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